

SANYO**CPH6102/CPH6202****High-Current Switching Applications****Applications**

- DC-DC converter, relay drivers, lamp drivers, motor drivers, strobes.

Features

- Adoption of FBET, MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package permitting applied sets to be made small and slim (0.9mm).
- High allowable power dissipation.

() : CPH6102

Specifications**Absolute Maximum Ratings** at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-60)	V
Collector-to-Emitter Voltage	V_{CE0}		(-50)	V
Emitter-to-Base Voltage	V_{EB0}		(-5)	V
Collector Current	I_C		(-1.0)	A
Collector Current (Pulse)	I_{CP}		(-2)	A
Collector Dissipation	P_C	Mounted on a ceramic board (600mm ² ×0.8mm)	1.3	W
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)50\text{V}, I_E = 0$			(-100)	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4\text{V}, I_C = 0$			(-100)	nA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2\text{V}, I_C = (-)100\text{mA}$	200		560	
	h_{FE2}	$V_{CE} = (-)2\text{V}, I_C = (-)1\text{A}$	30			
Gain-Bandwidth Product	f_T	$V_{CE} = (-)10\text{V}, I_C = (-)50\text{mA}$		150		MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10\text{V}, f = 1\text{MHz}$		(12)8.5		pF

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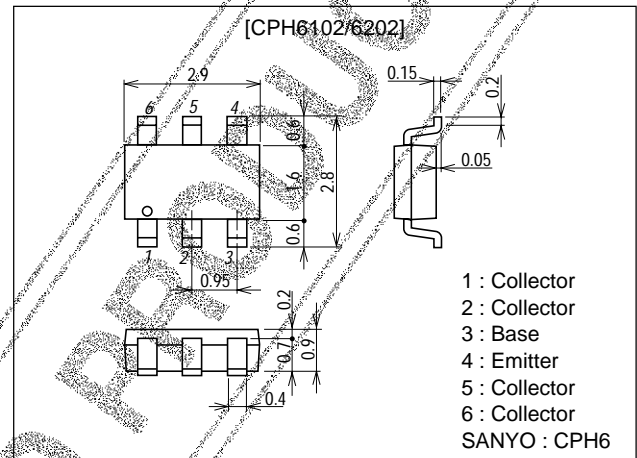
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Package Dimensions

unit:mm

2146A

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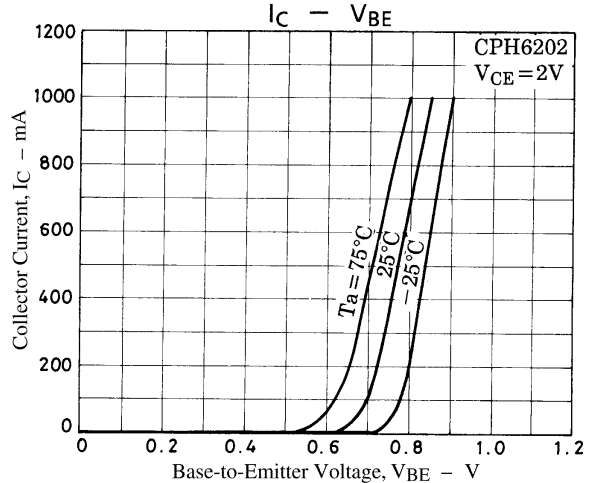
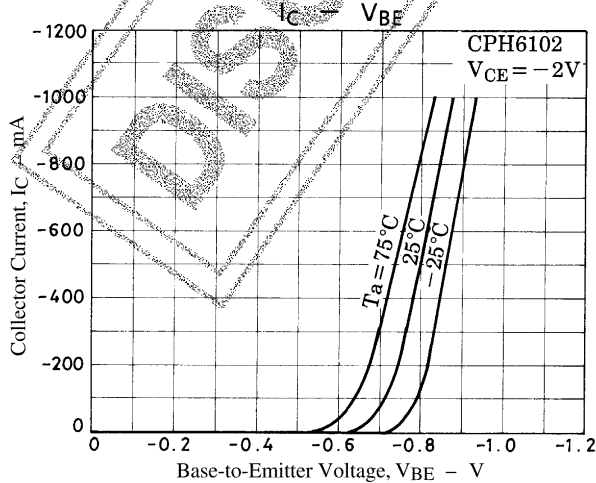
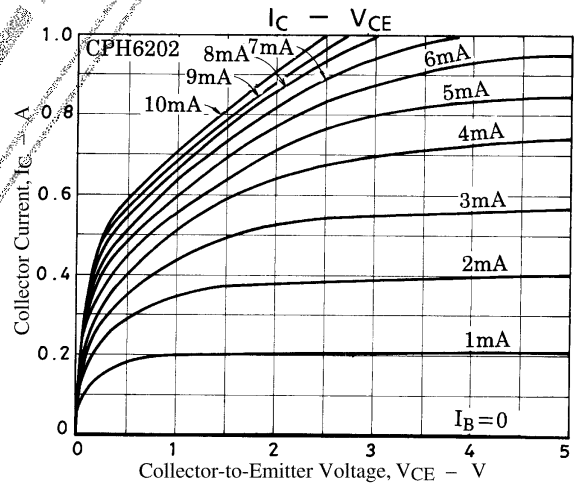
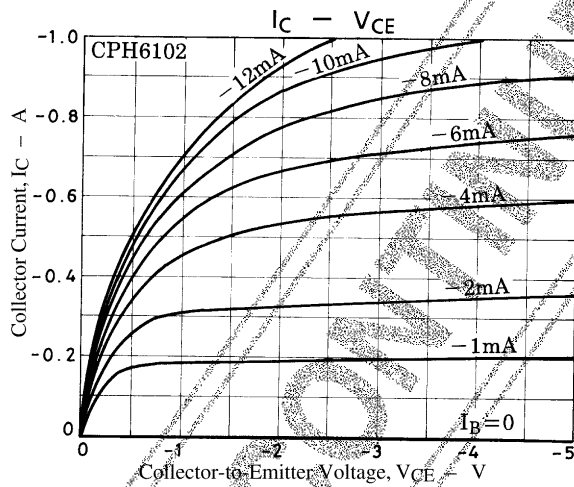
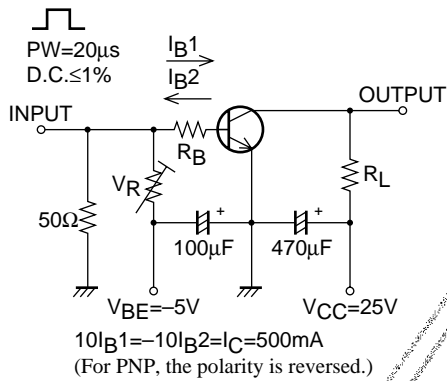
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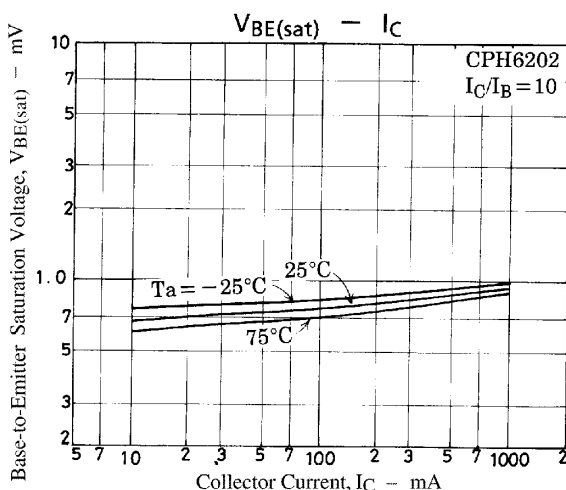
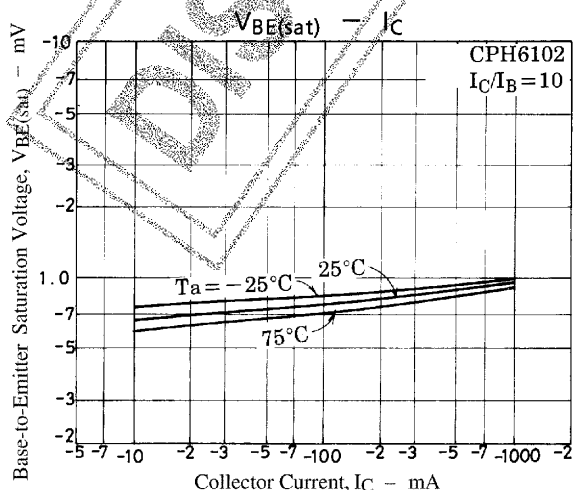
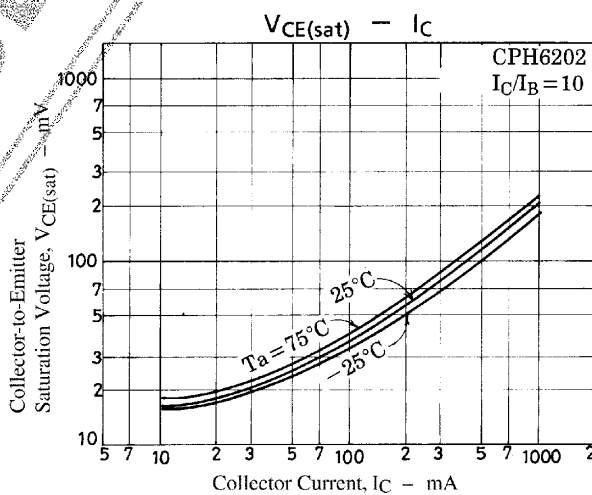
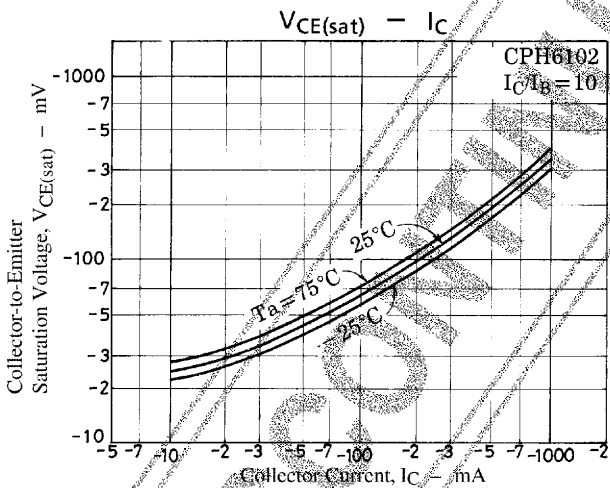
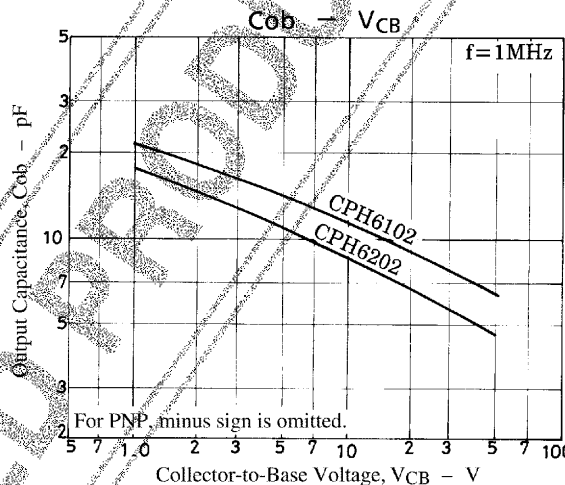
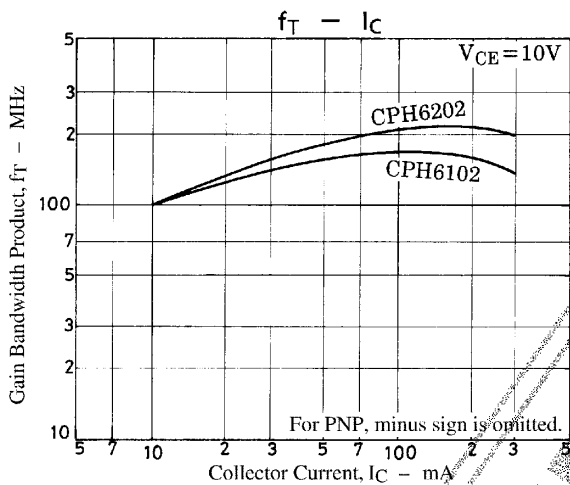
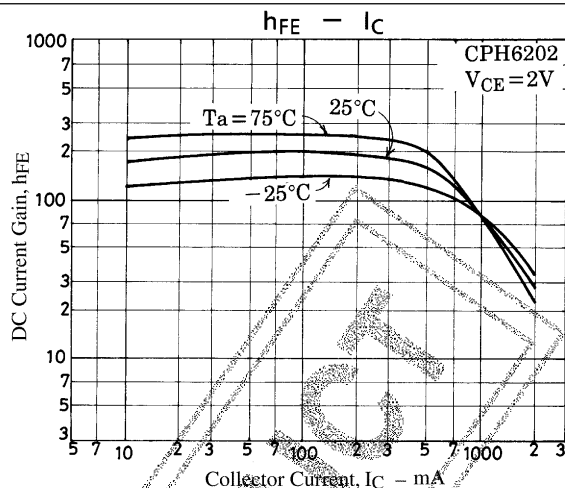
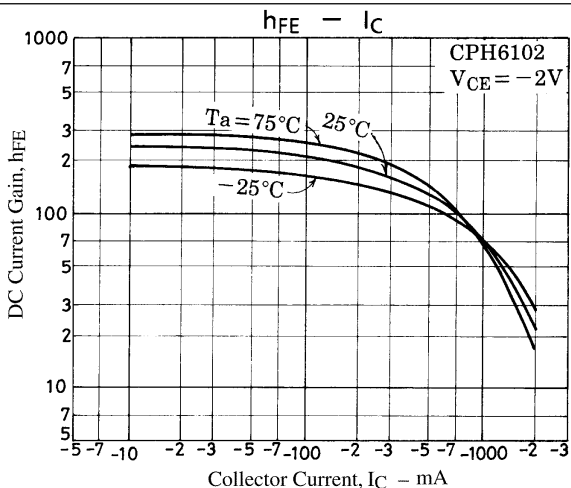
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)500mA, I_B=(-)50mA$		(-180)	(-500)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)500mA, I_B=(-)50mA$		120	300	mV
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-60)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_E=(-)1mA, R_{BE}=\infty$	(-50)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-5)			V
Turn-ON Time	t_{on}	See specified test circuit.		40(40)		ns
Storage Time	t_{stg}	See specified test circuit.		350		ns
Fall Time	t_f	See specified test circuit.		(300)		ns
				30(30)		ns

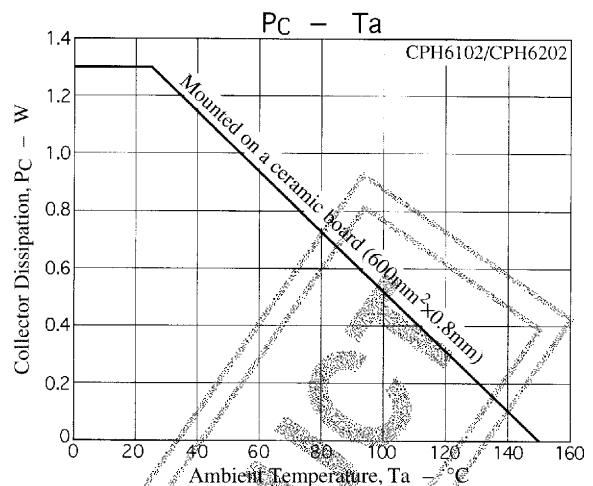
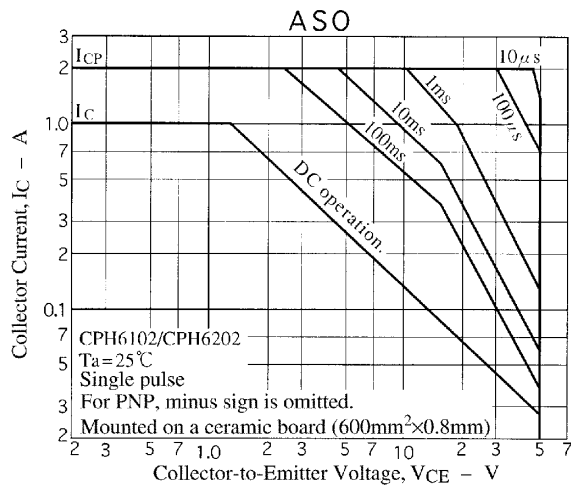
Switching Time Test Circuit



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